P-Channel 20-V (D-S) MOSFET

PRODUCT SUMMARY

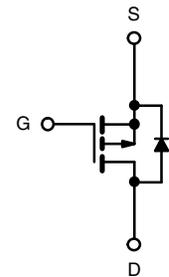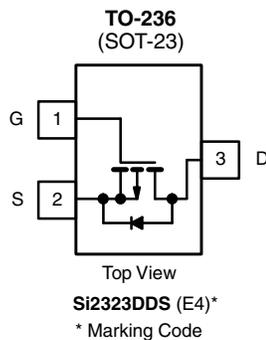| V_{DS} (V)	$R_{DS(on)}$ (Ω) Max.	I_D (A)[d]	Q_g (Typ.)
- 20	0.039 at V_{GS} = - 4.5 V	- 5.3	13.6 nC
	0.050 at V_{GS} = - 2.5 V	- 4.7	
	0.075 at V_{GS} = - 1.8 V	- 3.8	

FEATURES

- TrenchFET[®] Power MOSFET
- 100 % R_g Tested
- Material categorization:
  For definitions of compliance please see
  www.vishay.com/doc?99912

Pb-free

RoHS COMPLIANT

HALOGEN FREE

APPLICATIONS

- Load Switch
- PA Switch
- DC/DC Converters
- Power Management

TO-236
(SOT-23)

G 1
S 2
3 D

Top View

Si2323DDS (E4)*
* Marking Code

Ordering Information:
Si2323DDS-T1-GE3 (Lead (Pb)-free and Halogen-free)

P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T_A = 25 °C, unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V_{DS}	- 20	V
Gate-Source Voltage		V_{GS}	± 8	
Continuous Drain Current (T_J = 150 °C)	T_C = 25 °C	I_D	- 5.3	A
	T_C = 70 °C		- 4.3	
	T_A = 25 °C		- 4.1[a,b]	
	T_A = 70 °C		- 3.2[a,b]	
Pulsed Drain Current (t = 300 µs)		I_{DM}	- 20	
Continuous Source-Drain Diode Current	T_C = 25 °C	I_S	- 1.4	
	T_A = 25 °C		- 0.8[a,b]	
Maximum Power Dissipation	T_C = 25 °C	P_D	1.7	W
	T_C = 70 °C		1.1	
	T_A = 25 °C		0.96[a,b]	
	T_A = 70 °C		0.62[a,b]	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	- 55 to 150	°C

THERMAL RESISTANCE RATINGS

Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient[a, c]	t ≤ 5 s	R_{thJA}	100	130	°C/W
Maximum Junction-to-Foot (Drain)	Steady State	R_{thJF}	60	75	

Notes:
a. Surface mounted on 1" x 1" FR4 board.
b. t = 5 s.
c. Maximum under steady state conditions is 175 °C/W.
d. T_C = 25 °C.

Si2323DDS

Vishay Siliconix

SPECIFICATIONS (T_J = 25 °C, unless otherwise noted)

| Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V_{DS}	V_{GS} = 0 V, I_D = - 250 µA	- 20			V
V_{DS} Temperature Coefficient	$\Delta V_{DS}/T_J$	I_D = - 250 µA		- 13		mV/°C
$V_{GS(th)}$ Temperature Coefficient	$\Delta V_{GS(th)}/T_J$			- 2.8		
Gate-Source Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = - 250 µA	- 0.4		- 1	V
Gate-Source Leakage	I_{GSS}	V_{DS} = 0 V, V_{GS} = ± 8 V			± 100	nA
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS} = - 20 V, V_{GS} = 0 V			- 1	µA
		V_{DS} = - 20 V, V_{GS} = 0 V, T_J = 55 °C			- 10	
On-State Drain Current[a]	$I_{D(on)}$	$V_{DS} \leq$ - 5 V, V_{GS} = - 4.5 V	- 15			A
Drain-Source On-State Resistance[a]	$R_{DS(on)}$	V_{GS} = - 4.5 V, I_D = - 4.1 A		0.032	0.039	Ω
		V_{GS} = - 2.5 V, I_D = - 2 A		0.041	0.050	
		V_{GS} = - 1.8 V, I_D = - 1 A		0.058	0.075	
Forward Transconductance[a]	g_{fs}	V_{DS} = - 10 V, I_D = - 4.1 A		18		S
Dynamic[b]						
Input Capacitance	C_{iss}	V_{DS} = - 10 V, V_{GS} = 0 V, f = 1 MHz		1160		pF
Output Capacitance	C_{oss}			135		
Reverse Transfer Capacitance	C_{rss}			120		
Total Gate Charge	Q_g	V_{DS} = - 10 V, V_{GS} = - 8 V, I_D = - 4.1 A		24	36	nC
Total Gate Charge	Q_g	V_{DS} = - 10 V, V_{GS} = - 4.5 V, I_D = - 4.1 A		13.6	21	
Gate-Source Charge	Q_{gs}			2		
Gate-Drain Charge	Q_{gd}			2.2		
Gate Resistance	R_g	f = 1 MHz	2	10	20	Ω
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = - 10 V, R_L = 3.1 Ω $I_D \cong$ - 3.2 A, V_{GEN} = - 4.5 V, R_g = 1 Ω		24	36	ns
Rise Time	t_r			22	40	
Turn-Off Delay Time	$t_{d(off)}$			52	78	
Fall Time	t_f			11	20	
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = - 10 V, R_L = 3.1 Ω $I_D \cong$ - 3.2 A, V_{GEN} = - 8 V, R_g = 1 Ω		8	16	
Rise Time	t_r			9	18	
Turn-Off Delay Time	$t_{d(off)}$			58	87	
Fall Time	t_f			9	18	
Drain-Source Body Diode Characteristics						
Continuous Source-Drain Diode Current	I_S	T_C = 25 °C			- 1.4	A
Pulse Diode Forward Current	I_{SM}				- 20	
Body Diode Voltage	V_{SD}	I_S = - 3.2 A, V_{GS} = 0 V		- 0.79	- 1.2	V
Body Diode Reverse Recovery Time	t_{rr}	I_F = - 3.2 A, dI/dt = 100 A/µs, T_J = 25 °C		14	25	ns
Body Diode Reverse Recovery Charge	Q_{rr}			6	12	nC
Reverse Recovery Fall Time	t_a			8		ns
Reverse Recovery Rise Time	t_b			6		

Notes:
a. Pulse test; pulse width $\leq$ 300 µs, duty cycle $\leq$ 2 %.
b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
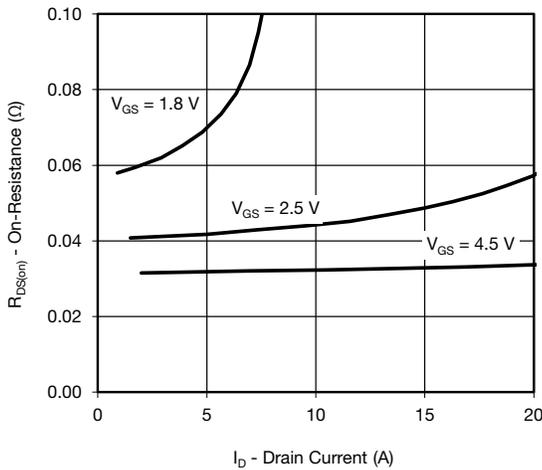
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)
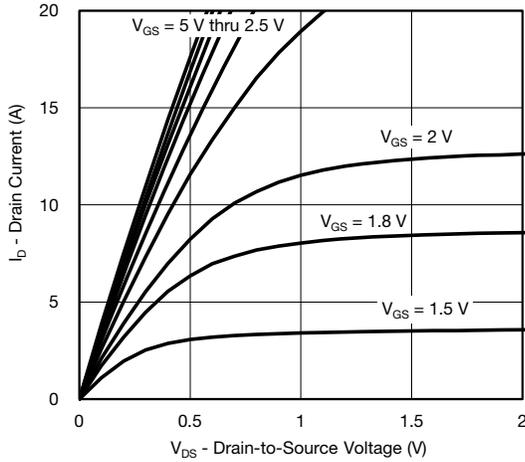
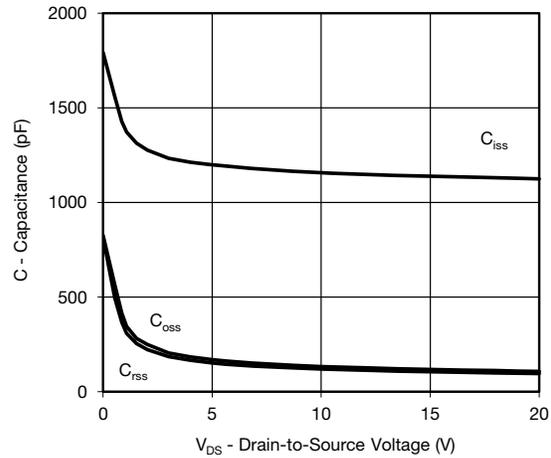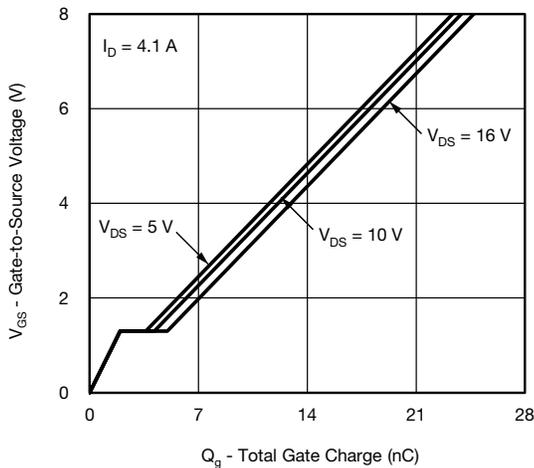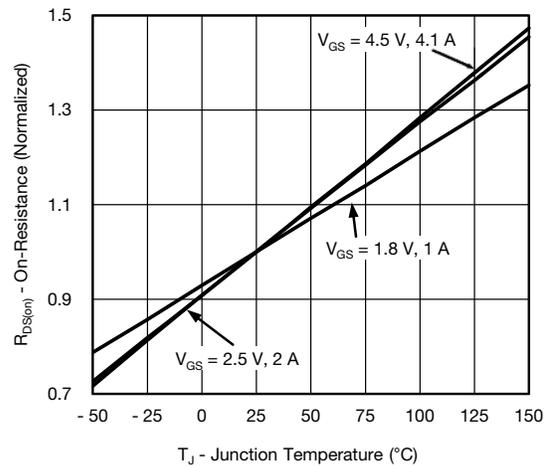**Output Characteristics**
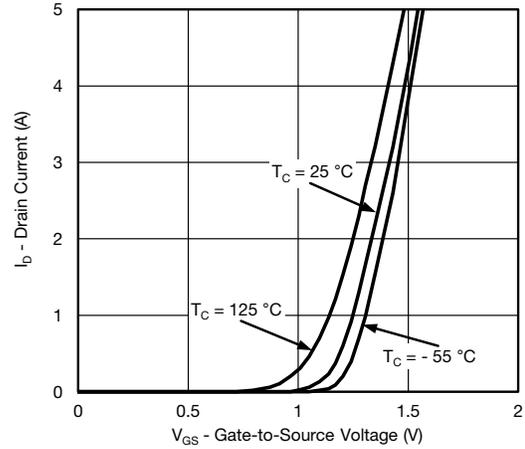
Transfer Characteristics

On-Resistance vs. Drain Current and Gate Voltage

Capacitance

Gate Charge

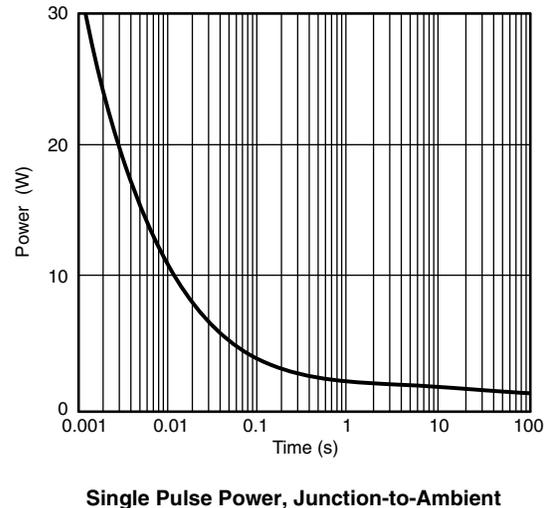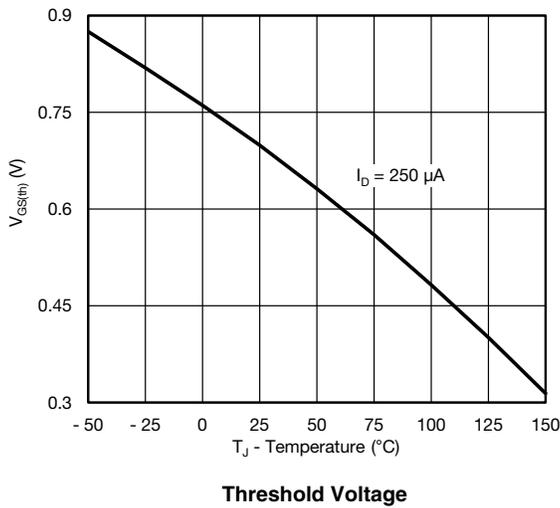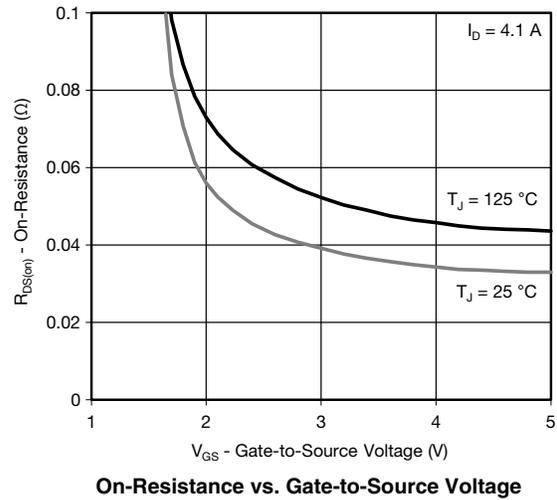**On-Resistance vs. Junction Temperature**

Document Number: 64004
S13-1165-Rev. A, 13-May-13

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Source-Drain Diode Forward Voltage

On-Resistance vs. Gate-to-Source Voltage

Threshold Voltage

Single Pulse Power, Junction-to-Ambient

Safe Operating Area, Junction-to-Ambient

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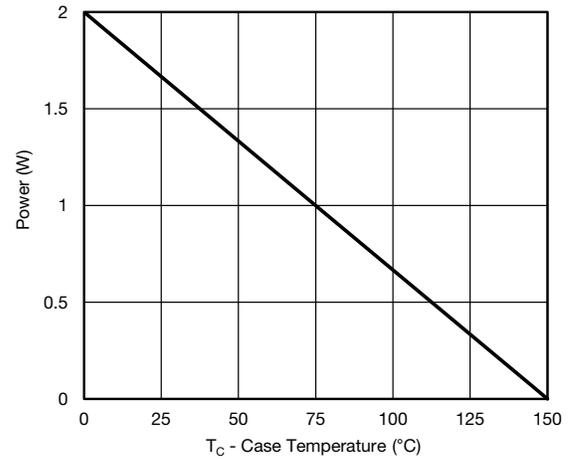For technical questions, contact: pmostechsupport@vishay.com

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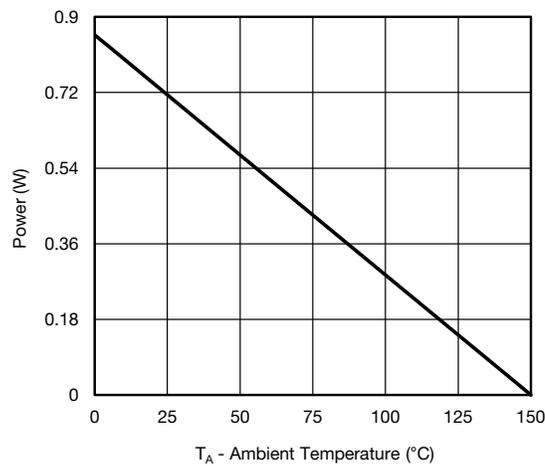
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)
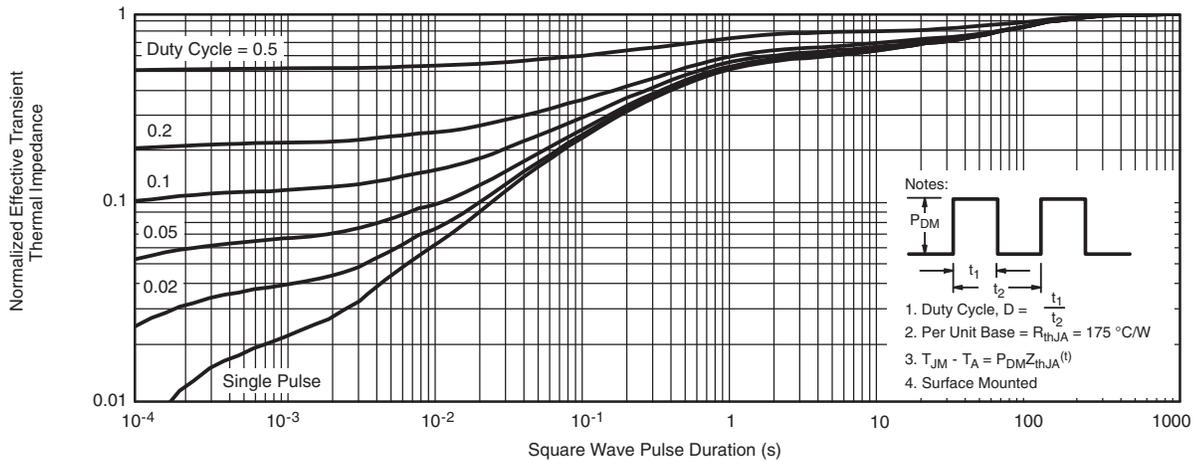
Current Derating*
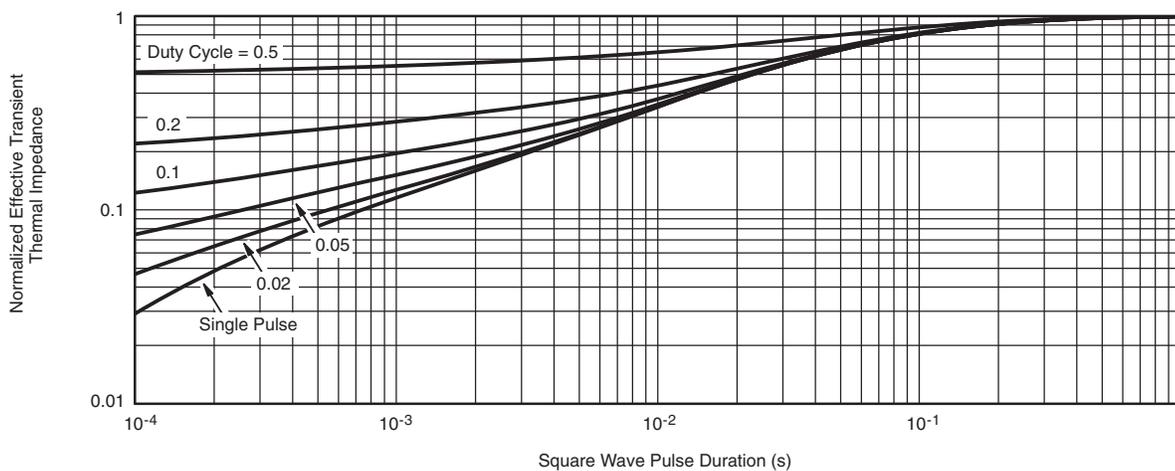
Power Derating, Junction-to-Foot

Power, Junction-to-Ambient

* The power dissipation P_D is based on $T_{J(max.)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

Notes:

1. Duty Cycle, D = $\frac{t_1}{t_2}$
2. Per Unit Base = R_{thJA} = 175 °C/W
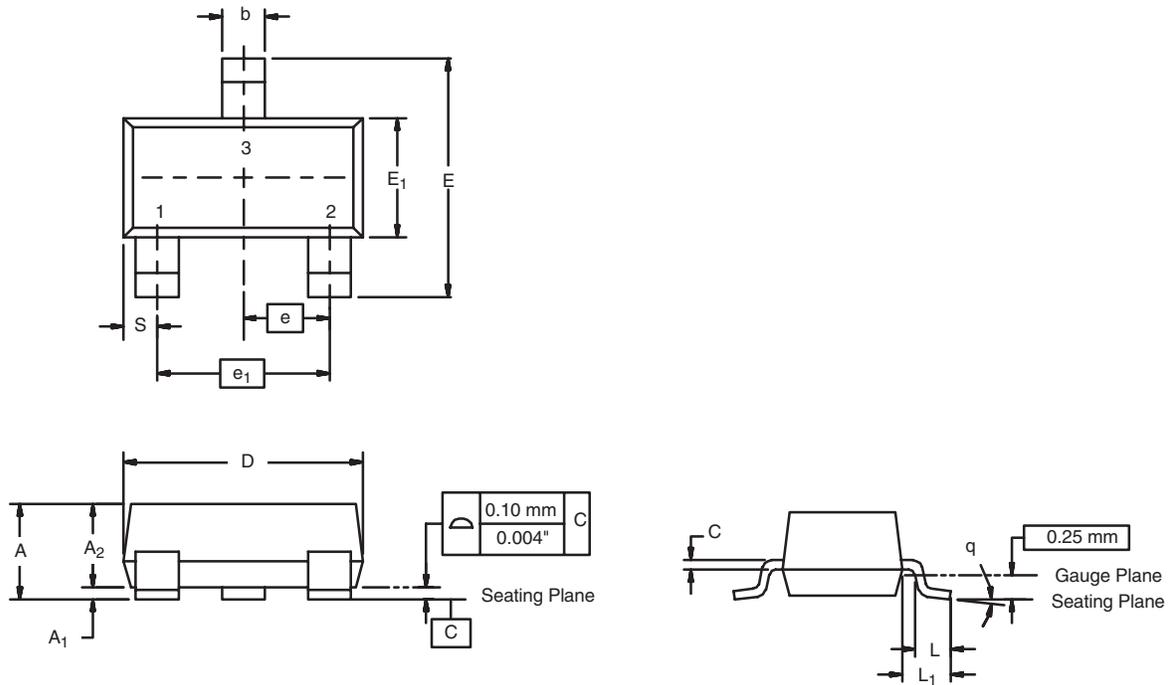3. $T_{JM} - T_A = P_{DM}Z_{thJA}^{(t)}$
4. Surface Mounted

Normalized Thermal Transient Impedance, Junction-to-Ambient

Normalized Thermal Transient Impedance, Junction-to-Foot

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SOT-23 (TO-236): 3-LEAD

Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A_1	0.01	0.10	0.0004	0.004
A_2	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E_1	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e_1	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L_1	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°
ECN: S-03946-Rev. K, 09-Jul-01 DWG: 5479				

RECOMMENDED MINIMUM PADS FOR SOT-23
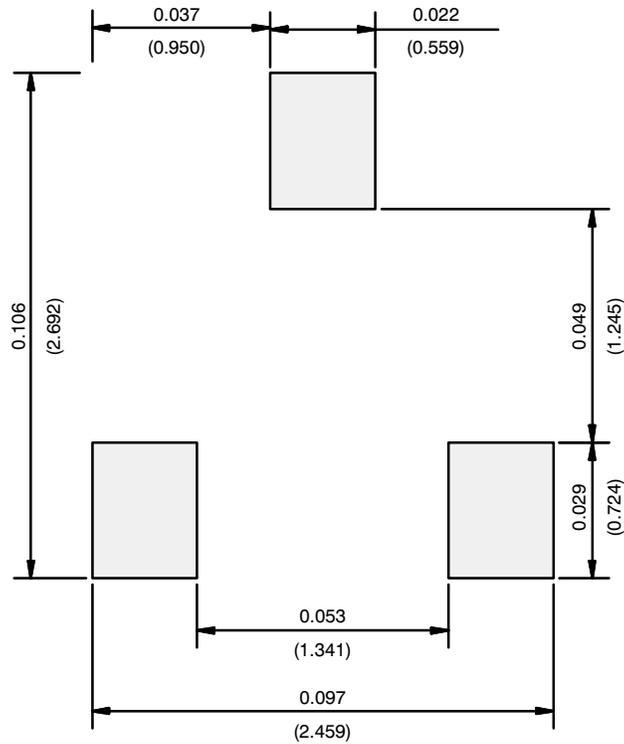
Recommended Minimum Pads
Dimensions in Inches/(mm)

APPLICATION NOTE

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